**DL PACKAGE** 

(TOP VIEW)

- Nine Differential Channels for the Data and Control Paths of the Differential Small Computer Systems Interface (SCSI)
- Meets or Exceeds the Requirements of ANSI Standard RS-485 and ISO 8482:1987(E)
- Packaged in Shrink Small-Outline Package With 25-mil Terminal Pitch
- Designed to Operate at 10 Million Transfers Per Second
- Low Disabled Supply Current 1.4 mA Typ
- Thermal Shutdown Protection
- Power-Up/Power-Down Glitch Protection
- Positive and Negative Output-Current Limiting
- Open-Circuit Fail-Safe Receiver Design

### description

The SN75LBC978 is a nine-channel differential transceiver based on the 75LBC176 LinASIC™ cell. Use of Tl's LinBiCMOS™† process technology allows the power reduction necessary to integrate nine differential balanced transceivers†. On-chip enabling logic makes this device applicable for the data path (eight data bits plus parity) and the control path (nine bits) for the Small Computer Systems Interface (SCSI) standard. The WRAP function allows in-circuit testing and wired-OR channels for the BSY, RST, and SEL signals of the SCSI bus.

The SN75LBC978 is packaged in a shrink small-outline package (DL) with improved thermal characteristics using heat-sink terminals. This package is ideal for low-profile, space-restricted applications such as hard disk drives.

NC [ 56 NC WRAP2 2 55 ¶ NC WRAP1 ∏ 3 54 Π CE 53 ¶ 9B+ 1A 📗 1DE/RE **1** 5 52**∏** 9B− 51 N 8B+ 2A | 2DE/RE 7 50 ¶ 8B− 8 49 **∏** 7B+ 3Α 3DE/RE 48**∏** 7B− 47 6B+ 4A [] 10 4DE/RE □ 11 46 ¶ 6B− 12 45 VCC  $V_{CC}$ GND [ 13 44 GND GND [ 14 43 **∏** GND GND [ 15 42 GND GND **1** 16 41 | GND GND I 17 40 ∏ GND 18 39 [] V<sub>CC</sub> V<sub>CC</sub> 19 38 5B+ 5A 20 37 5B-5DE/RE 21 36**∏** 4B+ 6A 22 35 AB-6DE/RE 23 34**∏** 3B+ 7A 24 33 ∏ 3B-7DE/RE 25 32 1 2B+ 8A 31 N 2B-26 8DE/RE 27 9A 28 <sup>29</sup>∏1B− 9DE/RE

Pins 13 through 17 and 40 through 44 are connected together to the package lead frame and signal ground.

The switching speed of the SN75LBC978 is sufficient to transfer data over the data bus at 10 million transfers per second. Each of the nine identical channels conforms to the requirements of the ANSI RS-485 and ISO 8482:1987(E) standards referenced by ANSI X3.131-1993 (SCSI-2) and the proposed SCSI-3 standards.

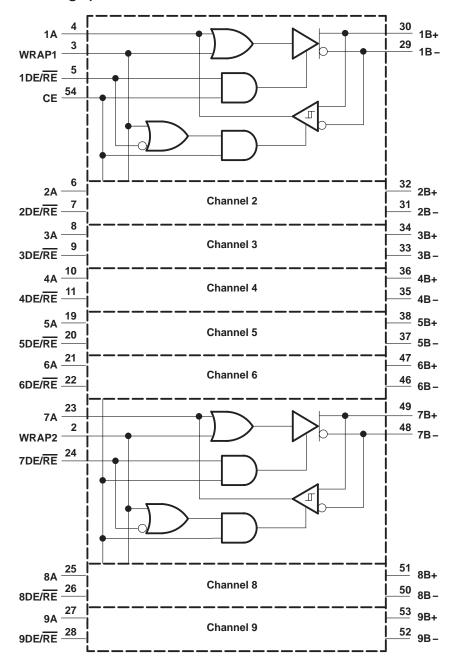
The SN75LBC978 is characterized for operation from 0°C to 70°C.

† Patent Pending

LinASIC and LinBiCMOS are trademarks of Texas Instruments Incorporated.

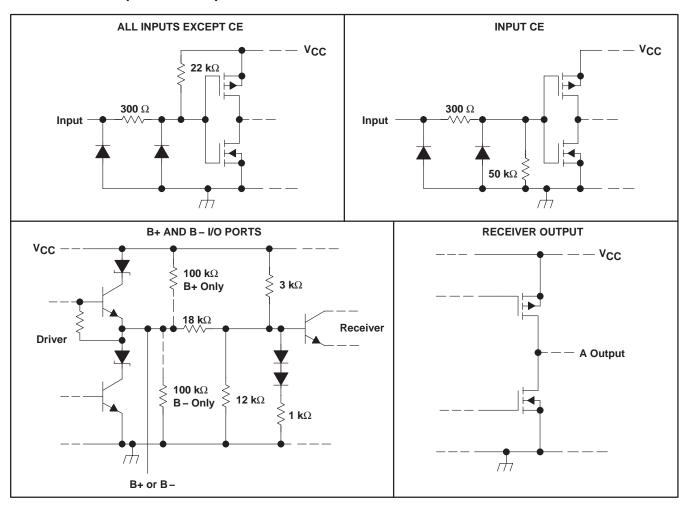


### logic diagram (positive logic)





### schematics of inputs and outputs



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub> (see Note 1) –0.3 V to 7 V
Bus voltage range
Data I/O and control (A-side) voltage range
Receiver output current, I <sub>O</sub> ±24 mA
Continuous power dissipation internally limited

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are dc and with respect to GND.



### SN75LBC978 9-CHANNEL DIFFERENTIAL TRANSCEIVER

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### recommended operating conditions

	MIN	NOM	MAX	UNIT	
Supply voltage, V <sub>CC</sub>	4.75	5	5.25	V	
Voltage at any hypothesis (consentative a consentative and a VV V conv	DD			12	.,
Voltage at any bus terminal (separately or common-mode), V <sub>O</sub> , V <sub>I</sub> , or V <sub>IC</sub>	B+ or B-			-7	V
High-level input voltage, VIH	All except B+ and B-	2			V
Low-level input voltage, V <sub>IL</sub>	All except B+ and B-			8.0	V
	B+ or B-			-60	mA
High-level output current, IOH	А			-8	mA
Low look activity arms of L	B+ or B-			60	mA
Low-level output current, IOL	A			8	mA
Operating free-air temperature, T <sub>A</sub>				70	°C

### device electrical characteristics over recommended ranges of operating conditions

	PARAME	TER	TES	T CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
	High laveliens to summer	A, WRAP, DE/RE		V. 2.V			-200	μΑ
ΙΗ	High-level input current	CE	]	V <sub>IH</sub> = 2 V			100	μΑ
	Law law Canadawana	A, WRAP, DE/RE	See Figure 1	See Figure 1			-200	μΑ
ll	Low-level input current	CE		V <sub>IL</sub> = 0.8 V			100	μΑ
	All drivers and receivers disabled  CE at 0 V  All receivers enabled  No load, VID = 5 V, CE at 5 V, WRAP and DE/RE at 0 V			1.4	3	mA		
Icc					29	45	mA	
		All drivers enabled	No load, WRAP at 0 V	CE and DE/RE at 5 V,		7	10	mA
CO	CO Bus port output capacitance		B+ or B-			19		pF
C .	0 . 5		One driver			460		pF
C <sub>pd</sub>	Power dissipation capacita	ance	One receiver			40		pF

## driver electrical characteristics over recommended ranges of operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
IVODI	Differential output voltage	V <sub>test</sub> = -7 V to 12 V, See Figure 2	1	2		V
los	Output short-circuit current	See Figure 3			±250	mA
loz	High-impedance-state output current	See receiver input current				

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### receiver electrical characteristics over recommended ranges of operating conditions (unless otherwise noted) (see Figure 3)

PARAMETER			TEST CONI	DITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Vон	OH High-level output voltage		$V_{ID} = 200 \text{ mV},$	$I_{OH} = -8 \text{ mA}$	2.5			V
VOL	Low-level output voltage		$V_{ID} = -200 \text{ mV},$	I <sub>OL</sub> = 8 mA			0.8	V
V <sub>IT+</sub>	Differential-input high-level t	hreshold voltage	$I_{OH} = -8 \text{ mA}$				0.2	V
$V_{IT-}$	Differential-input low-level th	reshold voltage	$I_{OL} = 8 \text{ mA}$		-0.2			V
V <sub>hys</sub>	Receiver input hysteresis vo	oltage (V <sub>IT+</sub> - V <sub>IT-</sub> )				45		mV
			V <sub>I</sub> = 12 V, Other input at 0 V	V <sub>CC</sub> = 5 V,		0.7	1	mA
	Baseline basel assessed	B B	$V_I = 12 \text{ V},$ Other input at 0 V	V <sub>CC</sub> = 0 V,		0.8	1	mA
li <sub>l</sub>	Receiver input current	B+ and B-	$V_I = -7 \text{ V},$ Other input at 0 V	V <sub>CC</sub> = 5 V,		-0.5	-0.8	mA
			$V_I = -7 \text{ V},$ Other input at 0 V	$V_{CC} = 0 V$ ,		-0.4	-0.8	mA
loz	High-impedance-state outpu	it current	$V_O = GND$				-200	μА
loz	r ligh-impedance-state outpo	it current	AO = ACC		·		50	μΑ

### driver switching characteristics over recommended ranges of operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		See Figure 4	11.8		26.4	
to high-level output (t <sub>d(ODL)</sub> ) to high-level output (t <sub>d(ODH)</sub> ) or low-	$V_{CC} = 5 \text{ V},  T_A = 25^{\circ}\text{C}$ See Figure 4	14	18	22	ns	
	to high lover output (td(ODE))	$V_{CC} = 5 \text{ V},  T_A = 70^{\circ}\text{C}$ See Figure 4	18	22	26	
	Skew limit, the maximum difference in propagation delay times				15	
tsk(lim)	between any two drivers on any two devices	$V_{CC} = 5 \text{ V}$ , See Note 2	2		8	ns
tsk(p)	Pulse skew ( t <sub>d</sub> (ODL) - t <sub>d</sub> (ODH) )	See Figure 4		0	6	ns
t <sub>t</sub>	Transition time (t <sub>r</sub> or t <sub>f</sub> )	See Figure 4		10		ns

### receiver switching characteristics over recommended ranges of operating conditions (unless otherwise noted)

	PARAMETER	TEST CON	MIN	TYP <sup>†</sup>	MAX	UNIT	
		See Figure 5		19.5		30.7	
<sup>t</sup> pd	Propagation delay time, high- to low-level output (tpHL) or low- to high-level output (tpLH)	V <sub>CC</sub> = 5 V, See Figure 5	$T_A = 25^{\circ}C$ ,	20.2	24.7	29.2	ns
	ingi lovoi odiput (tpLn)	V <sub>CC</sub> = 5 V, See Figure 5	$T_A = 70^{\circ}C$ ,	21.1	25.6	30.1	
	Skew limit, the maximum difference in propagation delay times					12	
<sup>t</sup> sk(lim)	between any two drivers on any two devices	V <sub>CC</sub> = 5 V,	See Note 2			9	ns
tsk(p)	Pulse skew ( tpHL - tpLH )	Can Figure F			2	6	ns
t <sub>t</sub>	Transition time (t <sub>r</sub> or t <sub>f</sub> )	See Figure 5			3		ns

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . ‡  $C_{pd}$  determines the no-load dynamic current consumption;  $I_S = C_{pd} \cdot V_{CC} \cdot f + I_{CC}$ . NOTE 2: This specification applies to any 5°C band within the operating temperature range.



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### transceiver switching characteristics over recommended ranges of operating conditions

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
ten(TXL)	Enable time, transmit-to-receive to low-level output			80	ns
ten(TXH)	Enable time, transmit-to-receive to high-level output			80	ns
ten(RXL)	Enable time, receive-to-transmit to low-level output	See Figure 6		150	ns
ten(RXH)	Enable time, receive-to-transmit to high-level output			150	ns
t <sub>su</sub>	Setup time, WRAP1 or WRAP2 before active input(s) or output(s)		150		ns

### thermal characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction-to-free-air thermal resistance	Board mounted, No air flow		50		°C/W
$R_{\theta JC}$	Junction-to-case thermal resistance			12		°C/W

### PARAMETER MEASUREMENT INFORMATION

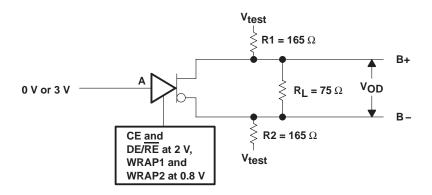
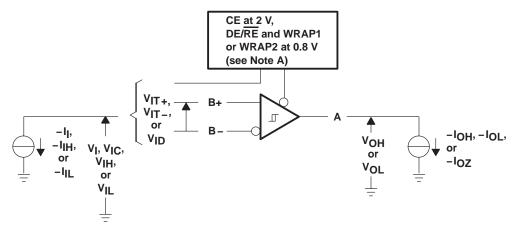


Figure 1. Driver V<sub>OD</sub> Test Circuit

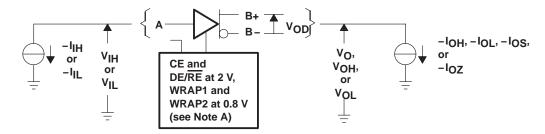


NOTE A: For the  $I_{\mbox{OZ}}$  measurement, CE is at 0.8 V.

Figure 2. Receiver Test Circuit and Input Conditions

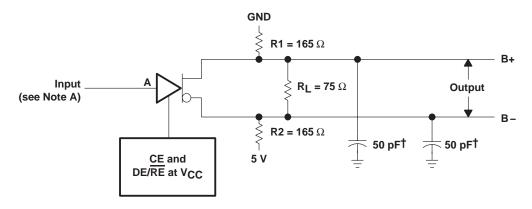


### PARAMETER MEASUREMENT INFORMATION

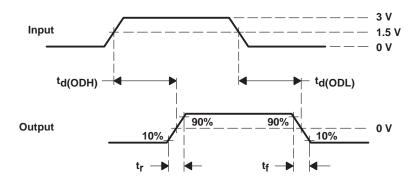


NOTE A: For the IOZ test, the CE input is at 0.8 V.

Figure 3. Driver Test and Input Conditions



### **TEST CIRCUIT**



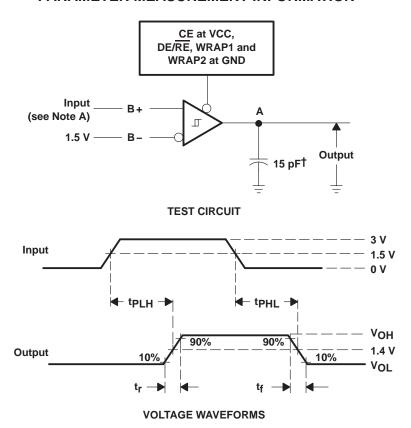
† Includes probe and jig capacitance.

NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle,  $t_f$  and  $t_f$  < 6 ns, and  $Z_O$  = 50  $\Omega$ .

**VOLTAGE WAVEFORMS** 

Figure 4. Driver Propagation Delay Time Test Circuit and Waveforms

### PARAMETER MEASUREMENT INFORMATION

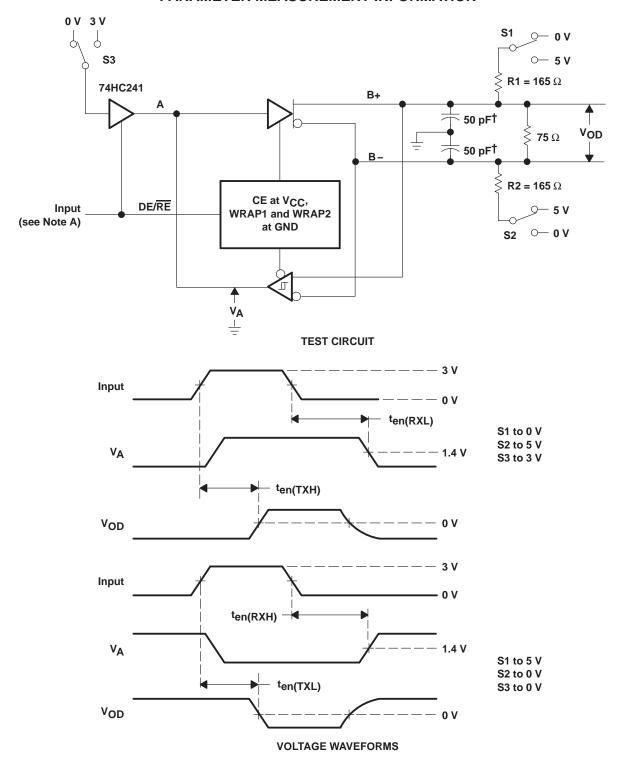


† Includes probe and jig capacitance.

NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle,  $t_\Gamma$  and  $t_f$  < 6 ns, and  $Z_O$  = 50  $\Omega$ .

Figure 5. Receiver Propagation Delay Time Test Circuit and Waveforms

### PARAMETER MEASUREMENT INFORMATION

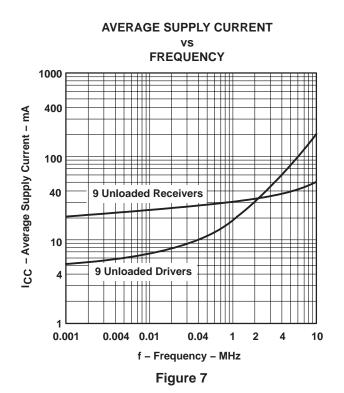


<sup>†</sup> Includes probe and jig capacitance.

NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle,  $t_f$  and  $t_f$  < 6 ns, and  $Z_O = 50 \Omega$ .

Figure 6. Enable Time Test Circuit and Voltage Waveforms





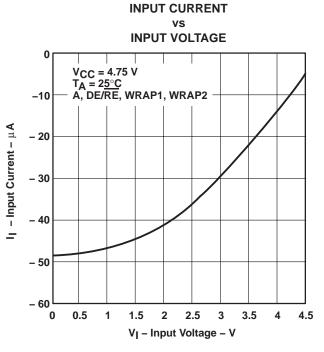
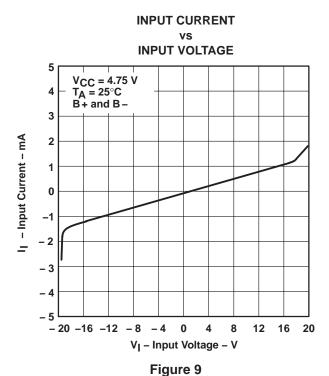
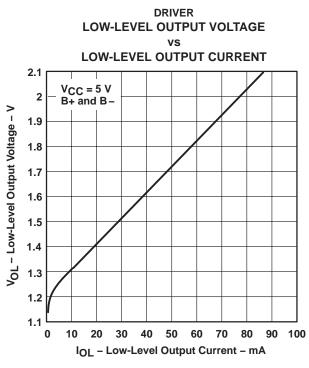


Figure 8







**DRIVER HIGH-LEVEL OUTPUT VOLTAGE HIGH-LEVEL OUTPUT CURRENT** 5 B+ and B-4.75 V<sub>OH</sub> - High-Level Output Voltage - mV 4.5 4.25  $V_{CC} = 5.25 \text{ V}$ 3.75  $V_{CC} = 5 V$ 3.5 3.25 3 2.75 V<sub>CC</sub> = 4.75 \ 2.5 0 20 30 40 50 70 80 90 IOH - High-Level Output Current - mA

Figure 10

Figure 11

### **DRIVER DIFFERENTIAL OUTPUT VOLTAGE** vs **OUTPUT CURRENT** 5 T<sub>A</sub> = 25°C VoD - Differential Output Voltage - V 3 $V_{CC} = 5 V$ 2 V<sub>CC</sub> = 5.25 V $V_{CC} = 4.75 \text{ V}$ 0 10 20 30 40 50 60 70 80 90 100 0 IO - Output Current - mA



Figure 12

- 80

2.5

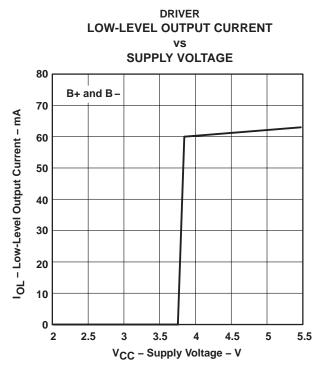


Figure 13

RECEIVER

### HIGH-LEVEL OUTPUT VOLTAGE **HIGH-LEVEL OUTPUT CURRENT** 5.5 5 V<sub>OH</sub> - High-Level Output Voltage - V 4.5 CC = 5.25 V V<sub>CC</sub> = 5 V 3.5 3 2.5 2 1.5 $V_{CC} = 4.75 V$ 0.5 - 30 0 - 20 - 40 - 50 IOH - High-Level Output Current - mA Figure 15

DRIVER **HIGH-LEVEL OUTPUT CURRENT SUPPLY VOLTAGE** 0 B+ and B--10IOH - High-Level Output Current - mA - 20 - 30 - 40 - 50 - 60 **- 70** 

Figure 14

3.5

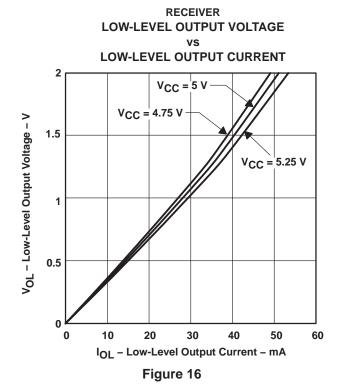
V<sub>CC</sub> - Supply Voltage - V

4.5

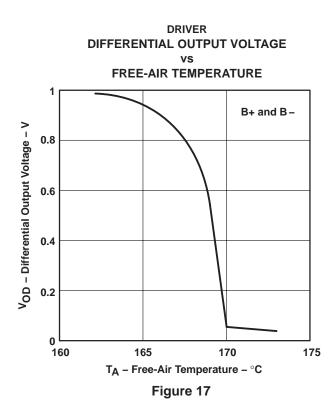
5

5.5

3







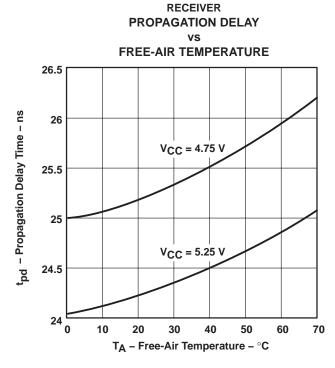


Figure 18

# DRIVER PROPAGATION DELAY TIME vs

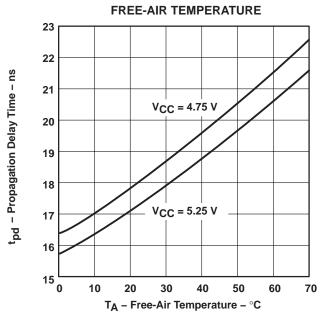




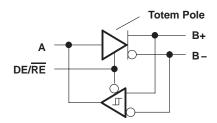
Figure 19

### **APPLICATION INFORMATION**

### function tables

Table 1. Channel Configuration for **Totem Pole Circuit** 

CE is high, WRAP1 or WRAP2 is low



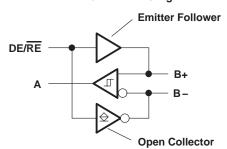
	INPU	0	UTPUT	S		
DE/RE	Α	B+†	в-†	Α	B+	B-
L	Х	L	Н	L	Z	Z
L	Χ	Н	L	Н	Z	Z
Н	L	X	Χ	Z	L	Н
Н	Н	Х	X X		Н	L

H = high level L = low level X = irrelevant Z = highimpedance

†An H in this column represents a voltage 200 mV higher than the other bus input. An L represents a voltage 200 mV lower than the other bus input. Any voltage less than 200 mV results in an indeterminate receiver output.

**Table 2. Channel Configuration for Emitter Follower Circuit** 

CE is high, WRAP1 or WRAP2 is high



IN	PUTS	0	UTPUT	S	
DE/RE	B+	Α	B+	B-	
L	L	Н	L	Z	Z
L	Н	L	Н	Z	Z
Н	Χ	X	Н	Н	L
Н	Χ	Χ	Н	Н	L

H = high level L = low level X = irrelevant Z = highimpedance

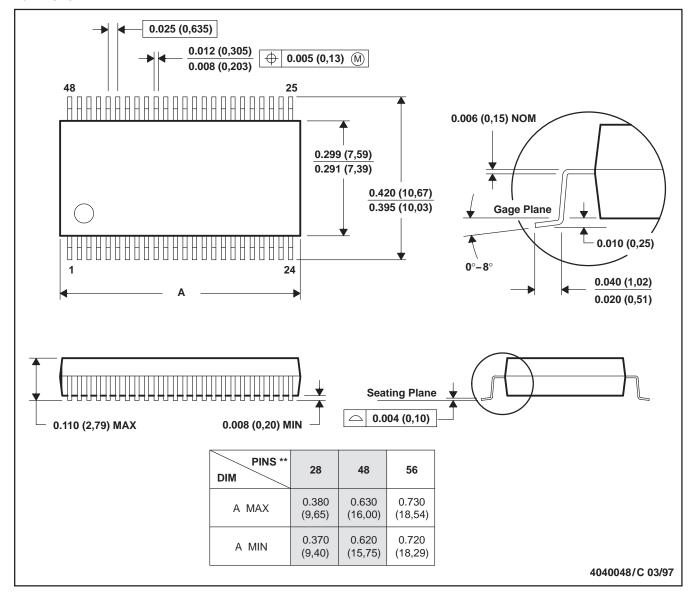


### **MECHANICAL INFORMATION**

### DL (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

### **48 PIN SHOWN**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118





.com 6-Dec-2006

### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN75LBC978DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC978DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC978DLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN75LBC978DLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

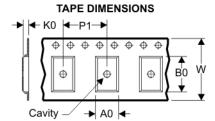
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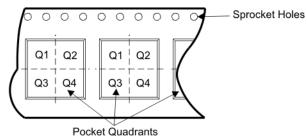
### TAPE AND REEL BOX INFORMATION

# REEL DIMENSIONS Reel Diameter Reel Widt



	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LBC978DLR	DL	56	SITE 41	330	32	11.35	18.67	3.1	16	32	Q1





Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
SN75LBC978DLR	DL	56	SITE 41	346.0	346.0	49.0

### DL (R-PDSO-G\*\*)

### **48 PINS SHOWN**

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

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